

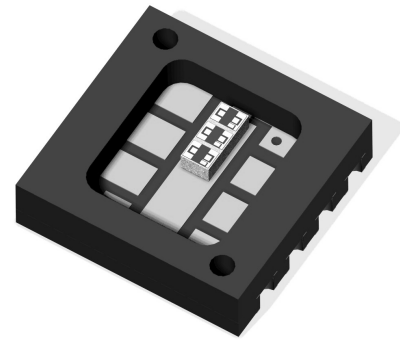
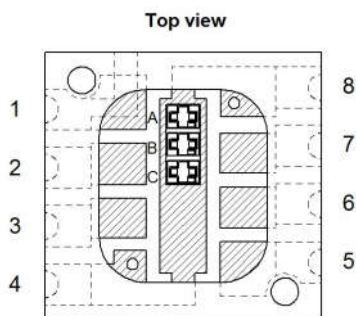
## General Description

OIT29 consists in a three elements silicon phototransistor's monolithic array.

The phototransistors have a common collector, every emitter is available as a pad. The pitch of the silicon arrays is 0.6 mm, while the component electrical pitch is 1.27 mm. The active area of each element is 0.2 x 0.45 mm. The encapsulant is an high quality microelectronic transparent silicone resin: its transmission value is greater than 95% between 300nm and 400nm while it is very close to 100% in the range 400-900nm. The phototransistors have an antireflective coating that guarantees a good spectral bandwith (500-950nm) with a peak responsivity at 755nm. The main advantages of this device are the high uniformity of the silicon sensors in all elctro-optical parameters, due to the monolithic construction and the high optical responsivity, due to the antireflective coating deposited on the phototransistor's areas.

## Applications

- Optical encoders
- Incremental encoders
- Optical Receivers
- Controls/drives



## Features

- High uniformity of silicon cells
- High transparency resin
- High gain
- Very small dimensions
- Reference dots on gold layer for very precise alignment
- Reference holes on frame for mechanical alignment

## Pin Functions

No.	Name	Function
1	AE	Phototransistor A Emitter
2	CE	Phototransistor C Emitter
3	N.C.	Not Connected
4	CC	Common collector
5	N.C.	Not Connected
6	N.C.	Not Connected
7	BE	Phototransistor B Emitter
8	CC	Common collector

## Ordering Information

OIT29	3-ch. phototransistor array 0.60mm optical pitch on plastic SMD package
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**ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Min	Max	Unit
T <sub>A</sub>	Operating Temperature Range	-40	85	°C
T <sub>S</sub>	Storage Temperature	-40	100	°C
T <sub>Sol</sub>	Lead Temperature (solder) 3s		360	°C
V <sub>R(BR)</sub>	Breakdown Voltage Collector-Emitter @ T <sub>A</sub> =25°C I <sub>B</sub> =100nA I <sub>C</sub> =1mA	50		V
P <sub>D</sub>	Power Dissipation @ T <sub>A</sub> =25°C		150	mW
ESDS	Electrostatic Discharge Susceptibility (Human Body Model, ESCC20800)		3	class

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

**ELECTRICAL CHARACTERISTICS**

T<sub>A</sub> = 25°C unless otherwise noted.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I <sub>D</sub>	Dark Current	V <sub>R</sub> =10V		5	100	nA
R <sub>λ</sub>	Responsivity	V <sub>CE</sub> =5V λ=755nm	0.5			A/W
λ <sub>p</sub>	Peak Responsivity	V <sub>CE</sub> =5V		755		nm
Δλ	Spectral Bandwidth @ 50%	V <sub>CE</sub> =5V	500		950	nm
I <sub>ec0</sub>	Reverse Emitter to Collector Current	V <sub>EC</sub> =7.7V		0.1	100	μA
I <sub>ce0</sub>	Collector-Emitter Current	V <sub>CE</sub> =52V		0.1	100	μA
H <sub>FE</sub>	Gain	V <sub>CC</sub> =5V I <sub>C</sub> =2mA	500	1000	2000	-
V <sub>CE(sat)</sub>	Saturation Voltage	I <sub>E</sub> =2mA I <sub>B</sub> =20μA		80	250	mV
I <sub>C(on)</sub>	On-state Collector Current	V <sub>CE</sub> =5V E <sub>E</sub> =1.0mW/cm <sup>2</sup>		1		mA
ΔI <sub>C</sub>	Interchannel variation	V <sub>CE</sub> =5V E <sub>E</sub> =1.0mW/cm <sup>2</sup>	-30		+30	%

**AC SWITCHING CHARACTERISTICS**

T<sub>A</sub> = 25°C hfe=1000 unless otherwise noted.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
t <sub>R</sub>	Rise Time	V <sub>CC</sub> =5V I <sub>C</sub> =1mA R <sub>L</sub> =1kΩ		10		μs
t <sub>F</sub>	Fall Time	V <sub>CC</sub> =5V I <sub>C</sub> =1mA R <sub>L</sub> =1kΩ		11		μs

**MECHANICAL CHARACTERISTICS**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
A	Phototransistor Active Area			0.09		mm <sup>2</sup>
L	Length of the Active Area			0.2		mm
W	Width of the Active Area			0.45		mm

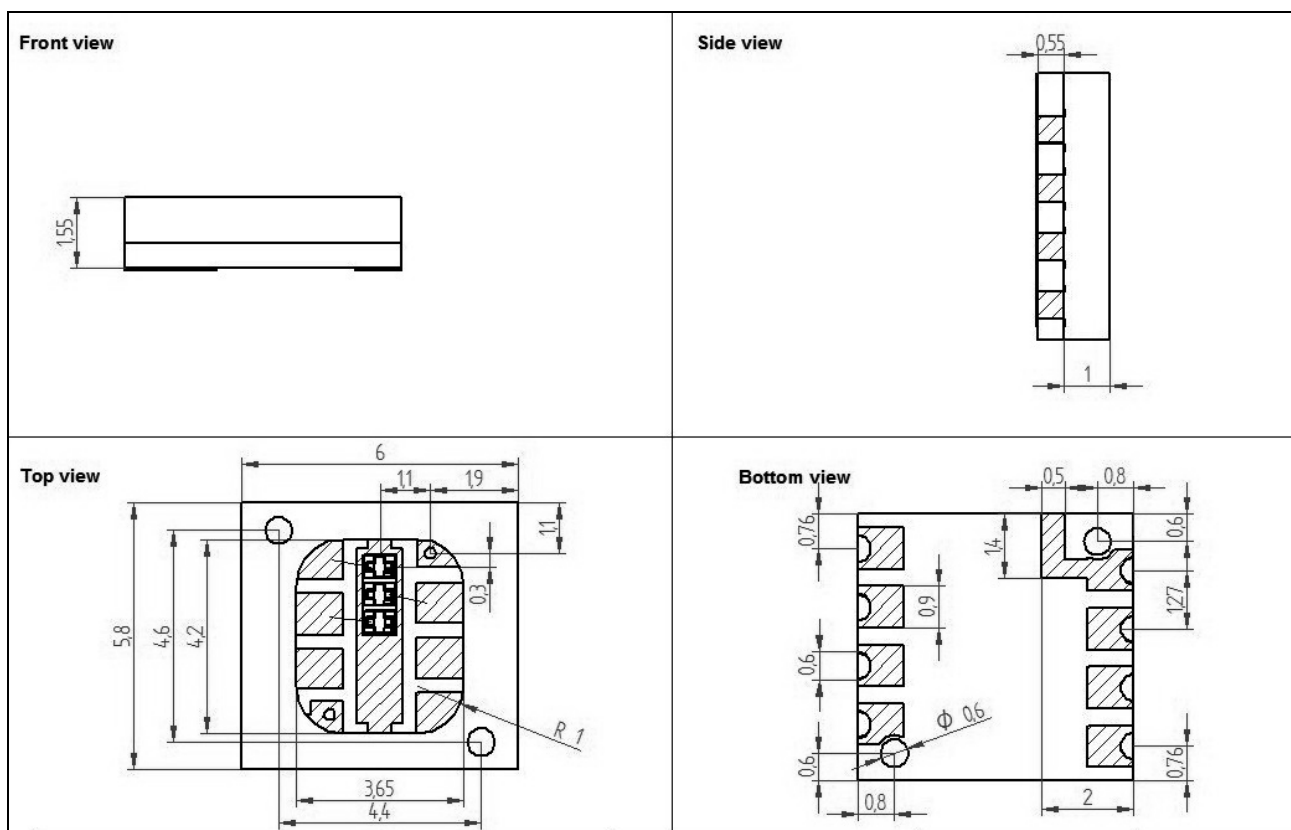
**PACKAGE CHARACTERISTICS**

Symbol	Parameter	Value	Unit
S <sub>F</sub>	Pad Surface Finishing	GOLD	
S <sub>L</sub>	Pad Shelf Life	6	months
MSL	Moisture Sensitive Level † (see note at bottom page)	3	level

† According to Jedec standard J-STD-020D.1

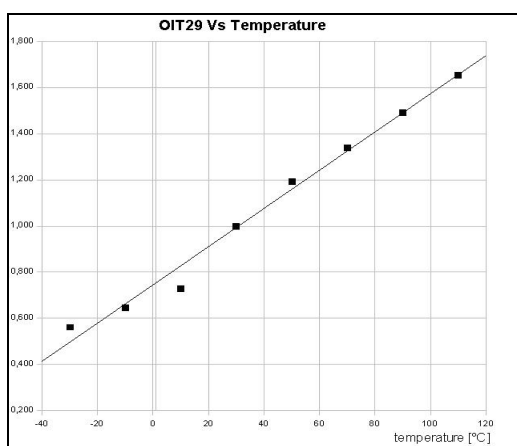
**MECHANICAL DIMENSIONS**

Units=mm Mechanical tolerances=+/-0.2mm Holes dim. and die positioning tolerance=+/-0.050mm



**TYPICAL PERFORMANCE CURVES**

**Figure 1 – Output voltage Vs Temperature**



**Figure 2 – Spectral Responsivity (h<sub>fe</sub>=1000)**

